

2.0V to 6.0V

35µA

<10nA

210mV at 300mA

# **LP5996** Dual Linear Regulator with 300mA and 150mA Outputs **General Description**

The LP5996 is a dual low dropout regulator. The first regulator can source 150mA, while the second is capable of sourcing 300mA.

The LP5996 provides 1.5% accuracy requiring an ultra low quiescent current of 35µA. Separate enable pins allow each output of the LP5996 to be shut down, drawing virtually zero current.

The LP5996 is designed to be stable with small footprint ceramic capacitors down to 1µF.

The LP5996 is available in fixed output voltages and comes in a 10 pin, 3mm x 3mm, LLP package. .

### Features

- 2 LDO Outputs with Independent Enable
- 1.5% Accuracy at Room Temperature, 3% over Temperature
- Thermal Shutdown Protection
- Stable with Ceramic Capacitors

## **Key Specifications**

- Input Voltage Range
- Low Dropout Voltage ■ Ultra-Low I<sub>O</sub> (enabled)
- Virtually Zero I<sub>Q</sub> (disabled)

## Package

All available in Lead Free option.

10 pin LLP 3mm x 3mm For other package options contact your NSC sales office.

## Applications

- Cellular Handsets
- PDA's
- Wireless Network Adaptors

## **Typical Application Circuit**



# **Functional Block Diagram**



#### \_\_\_\_

# **Pin Descriptions**

### LLP-10 Package

Pin No	Symbol	Name and Function
1	V <sub>IN</sub>	Voltage Supply Input. Connect a 1µF capacitor between this
		pin and GND.
2	EN1	Enable Input to Regulator 1. Active high input.
		High = On. Low = OFF.
3	EN2	Enable Input to Regulator 2. Active high input.
		High = On. Low = OFF.
4	C <sub>BYP</sub>	Internal Voltage Reference Bypass. Connect a 10nF capacitor
		from this pin to GND to reduce noise and improve line
		transient and PSRR.
		This pin may be left open.
5	N/C	No Connection. Do not connect to any other pin.
6	GND	Common Ground pin. Connect externally to exposed pad.
7	N/C	No Connection. Do not connect to any other pin.
8	N/C	No Connection. Do not connect to any other pin.
9	V <sub>OUT2</sub>	Output of Regulator 2. 300mA maximum current output.
		Connect a 1µF capacitor between this pin to GND.
10	V <sub>OUT1</sub>	Output of Regulator 1. 150mA maximum current output.
		Connect a 1µF capacitor between this pin to GND.
Pad	GND	Common Ground. Connect to Pin 6.

LP5996



# Ordering Information (LLP-10)

For other voltage options, please contact your local NSC sales office.

Output Voltage (V)	Order Number	Spec	Package Marking	Supplied As
0.8 / 3.3	LP5996SD-0833	NOPB	L176B	1000 Units, Tape-and-Reel
	LP5996SDX-0833	NOPB		4500 Units, Tape-and-Reel
	LP5996SD-0833			1000 Units, Tape-and-Reel
	LP5996SDX-0833			4500 Units, Tape-and-Reel
1.5 / 2.5	LP5996SD-1525	NOPB	L177B	1000 Units, Tape-and-Reel
	LP5996SDX-1525	NOPB		4500 Units, Tape-and-Reel
	LP5996SD-1525			1000 Units, Tape-and-Reel
	LP5996SDX-1525			4500 Units, Tape-and-Reel
2.8 / 2.8	LP5996SD-2828	NOPB	L180B	1000 Units, Tape-and-Reel
	LP5996SDX-2828	NOPB		4500 Units, Tape-and-Reel
	LP5996SD-2828			1000 Units, Tape-and-Reel
	LP5996SDX-2828			4500 Units, Tape-and-Reel
3.0 / 3.0	LP5996SD-3030	NOPB	L181B	1000 Units, Tape-and-Reel
	LP5996SDX-3030	NOPB		4500 Units, Tape-and-Reel
	LP5996SD-3030			1000 Units, Tape-and-Reel
	LP5996SDX-3030			4500 Units, Tape-and-Reel
3.0 / 3.3	LP5996SD-3033	NOPB	L179B	1000 Units, Tape-and-Reel
	LP5996SDX3033	NOPB		4500 Units, Tape-and-Reel
	LP5996SD-3033			1000 Units, Tape-and-Reel
	LP5996SDX3033			4500 Units, Tape-and-Reel
3.3 / 0.8	LP5996SD-3308	NOPB	L205B	1000 Units, Tape-and-Reel
	LP5996SDX-3308	NOPB		4500 Units, Tape-and-Reel
	LP5996SD-3308			1000 Units, Tape-and-Reel
	LP5996SDX-3308			4500 Units, Tape-and-Reel
3.3 / 3.3	LP5996SD-3333	NOPB	L182B	1000 Units, Tape-and-Reel
	LP5996SDX-3333	NOPB		4500 Units, Tape-and-Re
F	LP5996SD-333		1	1000 Units, Tape-and-Reel
	LP5996SDX-3333		1	4500 Units, Tape-and-Re

## **Absolute Maximum Ratings**

#### (Notes 1, 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Input Voltage	-0.3V to 6.5V
$V_{OUT1}$ , $V_{OUT2}$ , EN1, and EN2	-0.3V to (V <sub>IN</sub> + 0.3V) with
Voltage to GND	6.5V (max)
Junction Temperature (T <sub>J-MAX</sub> )	150°C
Lead/Pad Temp. (Note 3)	235°C
Storage Temperature	-65°C to 150°C
Continuous Power Dissipation	
Internally Limited(Note 4)	

ESD Rating(Note 5) Human Body Model 2.0kV Machine Model 200V

### **Operating Ratings**(Notes 1, 2)

Input Voltage	2.0V to 6.0V
EN1, EN2 Voltage	0 to (V <sub>IN</sub> + 0.3V) to
	6.0V (max)
Junction Temperature	-40°C to 125°C
Ambient Temperature T <sub>A</sub> Range	-40°C to 85°C
(Note 6)	

### Thermal Properties(Note 1)

Junction To Ambient Thermal Resistance(Note 7) θ<sub>JA</sub>LLP-10 Package

55°C/W

### Electrical Characteristics (Notes 2, 8)

Unless otherwise noted,  $V_{EN} = 950 \text{mV}$ ,  $V_{IN} = V_{OUT} + 1.0\text{V}$ , or 2.0V, whichever is higher, where  $V_{OUT}$  is the higher of  $V_{OUT1}$  and  $V_{OUT2}$ .  $C_{IN} = 1 \ \mu\text{F}$ ,  $I_{OUT} = 1 \ \text{mA}$ ,  $C_{OUT1} = C_{OUT2} = 1.0 \ \mu\text{F}$ . Typical values and limits appearing in normal type apply for  $T_A = 25^{\circ}\text{C}$ . Limits appearing in **boldface** type apply over the full junction temperature range for operation, -40 to +125°C.

Cumbal	Devementer	Conditions		Conditions		Turn	Li	Limit	
Symbol	Parameter	Conditions		тур	Min	Max	Units		
V <sub>IN</sub>	Input Voltage	(Note 9)			2	6	V		
ΔV <sub>OUT</sub>	Output Voltage Tolerance	I <sub>OUT</sub> = 1mA	$1.5V < V_{OUT} \le 3.3V$		-2.5	+2.5			
					-3.75	+3.75	0/_		
			$V_{OUT} \le 1.5V$		-2.75	+2.75	/0		
					-4	+4			
	Line Regulation Error	$V_{IN} = (V_{OUT(NC)})$	<sub>OM)</sub> + 1.0V) to 6.0V	0.03		0.3	%/V		
Load Regulation Error		I <sub>OUT</sub> = 1mA to 150mA (LDO 1)		85		155			
		I <sub>OUT</sub> = 1mA to 300mA (LDO 2)		26		85			
V <sub>DO</sub>	Dropout Voltage (Note 10)	I <sub>OUT</sub> = 1mA to (LDO 1)	150mA	110		220	m\/		
		I <sub>OUT</sub> = 1mA to 300mA (LDO 2)		210		550			
Ι <sub>Q</sub>	Quiescent Current	LDO 1 ON, LD I <sub>OUT1</sub> = I <sub>OUT2</sub> =	O 2 ON 0mA	35		100			
		LDO 1 ON, LDO 2 OFF I <sub>OUT1</sub> = 150mA LDO 1 OFF, LDO 2 ON I <sub>OUT2</sub> = 300mA		45		110			
				45		110			
		LDO 1 ON, LDO 2 ON I <sub>OUT1</sub> = 150mA, I <sub>OUT2</sub> = 300m		70		170			
		$V_{EN1} = V_{EN2} =$	0.4V	0.5		10	nA		
I <sub>sc</sub>	Short Circuit Current Limit	LDO 1		420		750			
		LDO 2		550		840	mA		
I <sub>OUT</sub>	Maximum Output Current	LDO 1			150		m 4		
		LDO 2			300		IIIA		

LP5996

### Electrical Characteristics(Notes 2, 8) (Continued)

Unless otherwise noted,  $V_{EN}$  = 950mV,  $V_{IN}$  =  $V_{OUT}$  + 1.0V, or 2.0V, whichever is higher, where  $V_{OUT}$  is the higher of  $V_{OUT1}$ and  $V_{OUT2}$ .  $C_{IN} = 1 \ \mu\text{F}$ ,  $I_{OUT} = 1 \ \text{mA}$ ,  $C_{OUT1} = C_{OUT2} = 1.0 \ \mu\text{F}$ . Typical values and limits appearing in normal type apply for  $T_A = 25^{\circ}\text{C}$ . Limits appearing in **boldface** type apply over the full junction temperature range for operation, -40 to +125^{\circ}\text{C}.

Symbol Baramotor		Conditions		Tun	Limit		Unite
Symbol	Parameter	0	naitions	Тур	Min	Мах	Units
PSRR	Power Supply Rejection Ratio (Note 11)	$f = 1 kHz, I_{OUT}$ = 1mA to	LDO1	58			
		150mA С <sub>вур</sub> = 10nF	LDO2	70			
		$f = 20kHz, I_{OUT}$ = 1mA to	LDO1	45			ab
		150mA С <sub>вче</sub> = 10nF	LDO2	60			-
e <sub>n</sub>	Output noise Voltage (Note 11)	BW = 10Hz to	$V_{OUT} = 0.8V$	36			
		$C_{BYP} = 10nF$	V <sub>OUT</sub> = 3.3V	75			μν <sub>RMS</sub>
T <sub>SHUTDOWN</sub>	Thermal Shutdown	Temperature		160			°C
		Hysteresis		20			
Enable Cont	trol Characteristics						
I <sub>EN</sub>	Input Current at $V_{EN1}$ or $V_{EN2}$	$V_{EN} = 0.0V$		0.005		0.1	
		$V_{EN} = 6V$		2		5	μΑ
V <sub>IL</sub>	Low Input Threshold					0.4	V
VIH	High Input Threshold				0.95		V
Timing Char	racteristics						
T <sub>ON</sub>	Turn On Time (Note 11)	To 95% Level С <sub>вур</sub> = 10nF		300			μs
Transient Response	Line Transient Response ΙδV <sub>OUT</sub> Ι (Note 11)	$T_{rise} = T_{fall} = 10$ $\delta V_{IN} = 1VC_{BYP} =$	us = 10nF	20			
	Load Transient Response ΙδV <sub>Ουτ</sub> Ι (Note 11)	T <sub>rise</sub> = T <sub>fall</sub> = 1μs	LDO 1 $I_{OUT} = 1mA$ to 150mA	175			mV (pk - pk)
			LDO 2 I <sub>OUT</sub> = 1mA to 300mA	150			

Note 1: Absolute Maximum Ratings are limits beyond which damage can occur. Operating Ratings are conditions under which operation of the device is guaranteed. Operating Ratings do not imply guaranteed performance limits. For guaranteed performance limits and associated test conditions, see the Electrical Characteristics tables

Note 2: All Voltages are with respect to the potential at the GND pin.

Note 3: For detailed soldering specifications and information, please refer to National Semiconductor Application Note AN-1187, Leadless Leadframe Package. Note 4: Internal thermal shutdown circuitry protects the device from permanent damage.

Note 5: The human body model is 100pF discharged through a 1.5k $\Omega$  resistor into each pin. The machine model is a 200pF capacitor discharged directly into each pin.

Note 6: The maximum ambient temperature ( $T_{A(max)}$ ) is dependant on the maximum operating junction temperature ( $T_{J(max-op)} = 125^{\circ}C$ ), the maximum power dissipation of the device in the application ( $P_{D(max)}$ ), and the junction to ambient thermal resistance of the part/package in the application ( $\theta_{JA}$ ), as given by the following equation:  $T_{A(max)} = T_{J(max-op)} - (\theta_{JA} \times P_{D(max)}).$ 

Note 7: Junction to ambient thermal resistance is dependant on the application and board layout. In applications where high maximum power dissipation is possible, special care must be paid to thermal dissipation issues in board design.

Note 8: Min Max limits are guaranteed by design, test or statistical analysis. Typical numbers are not guaranteed, but do represent the most likely norm.

Note 9: V<sub>IN(MIN)</sub> = V<sub>OUT(NOM)</sub> + 0.5V, or 2.0V, whichever is higher.

Note 10: Dropout voltage is voltage difference between input and output at which the output voltage drops to 100mV below its nominal value. This parameter only for output voltages above 2.0V

Note 11: This electrical specification is guaranteed by design.

Symbol	Devementer	Conditions	Nom	Limit		Unite
Symbol	Parameter	Conditions	NOM	Min	Max	Units
Cout	Output Capacitance	Capacitance (Note 12)	1.0	0.7		μF
		ESR		5	500	mΩ
Y5V and Z5U	can also be used. (See capacitor se	ction in Applications Hints).		rei, dependinų	on the applic	αιιση, Αθη,

**Typical Performance Characteristics.** Unless otherwise specified,  $C_{IN} = 1.0\mu$ F Ceramic,  $C_{OUT1} = C_{OUT2} = 1.0\mu$ F Ceramic,  $C_{BYP} = 10$ nF,  $V_{IN} = V_{OUT2(NOM)} + 1.0V$ ,  $T_A = 25^{\circ}$ C,  $V_{OUT1(NOM)} = 3.3V$ ,  $V_{OUT2(NOM)} = 3.3V$ , Enable pins are tied to  $V_{IN}$ .

#### **Output Voltage Change vs Temperature**





Ground Current vs Load Current, LDO2



Dropout Voltage vs  $I_{LOAD}$ , LDO1



#### Ground Current vs Load Current,LDO1



Ground Current vs  $V_{IN}$ ,  $I_{LOAD} = 1mA$ 



Dropout Voltage vs I<sub>LOAD</sub>, LDO2



**Typical Performance Characteristics.** Unless otherwise specified,  $C_{IN} = 1.0\mu$ F Ceramic,  $C_{OUT1} = C_{OUT2} = 1.0\mu$ F Ceramic,  $C_{BYP} = 10$ nF,  $V_{IN} = V_{OUT2(NOM)} + 1.0V$ ,  $T_A = 25$ °C,  $V_{OUT1(NOM)} = 3.3V$ ,  $V_{OUT2(NOM)} = 3.3V$ , Enable pins are tied to  $V_{IN}$ . (Continued)





**Typical Performance Characteristics.** Unless otherwise specified,  $C_{IN} = 1.0\mu$ F Ceramic,  $C_{OUT1} = C_{OUT2} = 1.0\mu$ F Ceramic,  $C_{BYP} = 10$ nF,  $V_{IN} = V_{OUT2(NOM)} + 1.0V$ ,  $T_A = 25^{\circ}$ C,  $V_{OUT1(NOM)} = 3.3V$ ,  $V_{OUT2(NOM)} = 3.3V$ , Enable pins are tied to  $V_{IN}$ . (Continued)





Power Supply Rejection Ratio, LDO2



Enable Start-up Time, C<sub>BYP</sub> = 10nF



20171561

## **Application Hints**

#### **OPERATION DESCRIPTION**

The LP5996 is a low quiescent current, power management IC, designed specifically for portable applications requiring minimum board space and smallest components. The LP5996 contains two independently selectable LDOs. The first is capable of sourcing 150mA at outputs between 0.8V and 3.3V. The second can source 300mA at an output voltage of 0.8V to 3.3V.

#### **INPUT CAPACITOR**

An input capacitor is required for stability. It is recommended that a  $1.0\mu$ F capacitor be connected between the LP5996 input pin and ground (this capacitance value may be increased without limit).

This capacitor must be located a distance of not more than 1cm from the input pin and returned to a clean analogue ground. Any good quality ceramic, tantalum, or film capacitor may be used at the input.

**Important:** Tantalum capacitors can suffer catastrophic failures due to surge current when connected to a low-impedance source of power (like a battery or a very large capacitor). If a tantalum capacitor is used at the input, it must be guaranteed by the manufacturer to have a surge current rating sufficient for the application.

There are no requirements for the ESR (Equivalent Series Resistance) on the input capacitor, but tolerance and temperature coefficient must be considered when selecting the capacitor to ensure the capacitance will remain approximately  $1.0\mu$ F over the entire operating temperature range.

#### **OUTPUT CAPACITOR**

The LP5996 is designed specifically to work with very small ceramic output capacitors. A  $1.0\mu$ F ceramic capacitor (temperature types Z5U, Y5V or X7R) with ESR between  $5m\Omega$  to  $500m\Omega$ , is suitable in the LP5996 application circuit.

For this device the output capacitor should be connected between the  $V_{\rm OUT}$  pin and ground.

It is also possible to use tantalum or film capacitors at the device output,  $C_{OUT}$  (or  $V_{OUT}$ ), but these are not as attractive for reasons of size and cost (see the section Capacitor Characteristics).

The output capacitor must meet the requirement for the minimum value of capacitance and also have an ESR value that is within the range  $5m\Omega$  to  $500m\Omega$  for stability.

#### **NO-LOAD STABILITY**

The LP5996 will remain stable and in regulation with no external load. This is an important consideration in some circuits, for example CMOS RAM keep-alive applications.

#### **CAPACITOR CHARACTERISTICS**

The LP5996 is designed to work with ceramic capacitors on the output to take advantage of the benefits they offer. For capacitance values in the range of  $0.47\mu$ F to  $4.7\mu$ F, ceramic capacitors are the smallest, least expensive and have the lowest ESR values, thus making them best for eliminating high frequency noise. The ESR of a typical  $1.0\mu$ F ceramic capacitor is in the range of  $20m\Omega$  to  $40m\Omega$ , which easily meets the ESR requirement for stability for the LP5996.

For both input and output capacitors, careful interpretation of the capacitor specification is required to ensure correct device operation. The capacitor value can change greatly, depending on the operating conditions and capacitor type.

In particular, the output capacitor selection should take account of all the capacitor parameters, to ensure that the specification is met within the application. The capacitance can vary with DC bias conditions as well as temperature and frequency of operation. Capacitor values will also show some decrease over time due to aging. The capacitor parameters are also dependant on the particular case size, with smaller sizes giving poorer performance figures in general. As an example, Figure 1 shows a typical graph comparing different capacitor case sizes in a Capacitance vs. DC Bias plot. As shown in the graph, increasing the DC Bias condition can result in the capacitance value falling below the minimum value given in the recommended capacitor specifications table (0.7µF in this case). Note that the graph shows the capacitance out of spec for the 0402 case size capacitor at higher bias voltages. It is therefore recommended that the capacitor manufacturers' specifications for the nominal value capacitor are consulted for all conditions, as some capacitor sizes (e.g. 0402) may not be suitable in the actual application.



# FIGURE 1. Graph Showing a Typical Variation in Capacitance vs DC Bias

The capacitance value of ceramic capacitors varies with temperature. The capacitor type X7R, which operates over a temperature range of -55°C to +125°C, will only vary the capacitance to within  $\pm$ 15%. The capacitor type X5R has a similar tolerance over a reduced temperature range of -55°C to +85°C. Many large value ceramic capacitors, larger than 1µF are manufactured with Z5U or Y5V temperature characteristics. Their capacitance can drop by more than 50% as the temperature varies from 25°C to 85°C. Therefore X7R is recommended over Z5U and Y5V in applications where the ambient temperature will change significantly above or below 25°C.

Tantalum capacitors are less desirable than ceramic for use as output capacitors because they are more expensive when comparing equivalent capacitance and voltage ratings in the  $0.47\mu$ F to  $4.7\mu$ F range.

Another important consideration is that tantalum capacitors have higher ESR values than equivalent size ceramics. This means that while it may be possible to find a tantalum

11

### Application Hints (Continued)

capacitor with an ESR value within the stable range, it would have to be larger in capacitance (which means bigger and more costly) than a ceramic capacitor with the same ESR value. It should also be noted that the ESR of a typical tantalum will increase about 2:1 as the temperature goes from 25°C down to -40°C, so some guard band must be allowed.

#### ENABLE CONTROL

The LP5996 features active high enable pins for each regulator, EN1 and EN2, which turns the corresponding LDO off when pulled low. The device outputs are enabled when the enable pins are set to high. When not enabled the regulator output is off and the device typically consumes 2nA.

If the application does not require the Enable switching feature, one or both enable pins should be tied to  $V_{\rm IN}$  to keep the regulator output permanently on.

To ensure proper operation, the signal source used to drive the enable inputs must be able to swing above and below the specified turn-on/off voltage thresholds listed in the Electrical Characteristics section under V<sub>IL</sub> and V<sub>IH</sub>.

#### BYPASS CAPACITOR

The internal voltage reference circuit of the LP5996 is connected to the  $C_{\rm BYP}$  pin via a high value internal resistor. An external capacitor, connected to this pin, forms a low-pass

filter which reduces the noise level on both outputs of the device. There is also some improvement in PSSR and line transient performance. Internal circuitry ensures rapid charging of the  $C_{\rm BYP}$  capacitor during start-up. A 10nF, high quality ceramic capacitor with either NPO or COG dielectric is recommended due to their low leakage characteristics and low noise performance.

#### SAFE AREA OF OPERATION

Due consideration should be given to operating conditions to avoid excessive thermal dissipation of the LP5996 or triggering its thermal shutdown circuit. When both outputs are enabled, the total power dissipation will be  $P_{D(LDO1)} + P_{D(LDO2)}$  where PD = (V<sub>IN</sub> - V<sub>OUT</sub>) x I<sub>OUT</sub> for each LDO

In general, device options which have a large difference in output voltage will dissipate more power with both outputs enabled, due to the input voltage required for the higher output voltage LDO. In such cases, especially at elevated ambient temperature, it may not be possible to operate both outputs at maximum current at the same time.



THE CONTENTS OF THIS DOCUMENT ARE PROVIDED IN CONNECTION WITH NATIONAL SEMICONDUCTOR CORPORATION ("NATIONAL") PRODUCTS. NATIONAL MAKES NO REPRESENTATIONS OR WARRANTIES WITH RESPECT TO THE ACCURACY OR COMPLETENESS OF THE CONTENTS OF THIS PUBLICATION AND RESERVES THE RIGHT TO MAKE CHANGES TO SPECIFICATIONS AND PRODUCT DESCRIPTIONS AT ANY TIME WITHOUT NOTICE. NO LICENSE, WHETHER EXPRESS, IMPLIED, ARISING BY ESTOPPEL OR OTHERWISE, TO ANY INTELLECTUAL PROPERTY RIGHTS IS GRANTED BY THIS DOCUMENT.

TESTING AND OTHER QUALITY CONTROLS ARE USED TO THE EXTENT NATIONAL DEEMS NECESSARY TO SUPPORT NATIONAL'S PRODUCT WARRANTY. EXCEPT WHERE MANDATED BY GOVERNMENT REQUIREMENTS, TESTING OF ALL PARAMETERS OF EACH PRODUCT IS NOT NECESSARILY PERFORMED. NATIONAL ASSUMES NO LIABILITY FOR APPLICATIONS ASSISTANCE OR BUYER PRODUCT DESIGN. BUYERS ARE RESPONSIBLE FOR THEIR PRODUCTS AND APPLICATIONS USING NATIONAL COMPONENTS. PRIOR TO USING OR DISTRIBUTING ANY PRODUCTS THAT INCLUDE NATIONAL COMPONENTS, BUYERS SHOULD PROVIDE ADEQUATE DESIGN, TESTING AND OPERATING SAFEGUARDS.

EXCEPT AS PROVIDED IN NATIONAL'S TERMS AND CONDITIONS OF SALE FOR SUCH PRODUCTS, NATIONAL ASSUMES NO LIABILITY WHATSOEVER, AND NATIONAL DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY RELATING TO THE SALE AND/OR USE OF NATIONAL PRODUCTS INCLUDING LIABILITY OR WARRANTIES RELATING TO FITNESS FOR A PARTICULAR PURPOSE, MERCHANTABILITY, OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

#### LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS PRIOR WRITTEN APPROVAL OF THE CHIEF EXECUTIVE OFFICER AND GENERAL COUNSEL OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

Life support devices or systems are devices which (a) are intended for surgical implant into the body, or (b) support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in a significant injury to the user. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system or to affect its safety or effectiveness.

National Semiconductor and the National Semiconductor logo are trademarks or registered trademarks of National Semiconductor Corporation. All other brand or product names may be trademarks or registered trademarks of their respective holders.

Copyright © 2006 National Semiconductor Corporation.

For the most current product information visit us at www.national.com.

National Semiconductor Americas Customer Support Center Email: new.feedback@nsc.com Tel: 1-800-272-9959

National Semiconductor Europe Customer Support Center Fax: +49 (0) 180-530 85 86 Email: europe.support@nsc.com Deutsch Tel: +449 (0) 69 9508 6208 English Tel: +444 (0) 870 24 0 2171 Français Tel: +33 (0) 1 41 91 8790 National Semiconductor Asia Pacific Customer Support Center Email: ap.support@nsc.com National Semiconductor Japan Customer Support Center Fax: 81-3-5639-7507 Email: jpn.feedback@nsc.com Tel: 81-3-5639-7560

www.national.com